



WHITE LED STEP-UP CONVERTER

AP3030

General Description

The AP3030 is an inductor-based DC/DC converter designed to drive up to eight white LEDs in series or 2 rows of LEDs with 5 for each in parallel for backlight. Only one feedback resistor is needed to control the LED current and obtain required brightness.

A constant frequency 1.2MHz PWM control scheme is employed in this IC, which means tiny external components can be used. Specifically, 1mm tall inductor and 0.22 μ F output capacitor for a typical application are sufficient. Additionally, the schottky diode in boost circuit is integrated on this chip. AP3030 also provides a disable pin to ease its use for different systems.

The output over-voltage protection is implemented in AP3030. When any LED is broken or in other abnormal conditions, the output voltage will be clamped to 30V.

The AP3030 is available in standard SOT-23-6 and TSOT-23-6 packages.

Features

- Inherently Uniform LED Current
- High Efficiency up to 84%
- No Need for External Schottky Diode
- Output Over-Voltage Protection (OVP)
- Drives up to 8 LEDs in Series or 2 Rows of LEDs with 5 for Each in Parallel
- Fixed 1.2MHz Switching Frequency
- Uses Tiny 1mm Tall Inductor
- Requires Only 0.22 μ F Output Capacitor

Applications

- Cellular Phones
- Digital Cameras
- LCD modules
- GPS Receivers
- PDAs, Handheld Computers

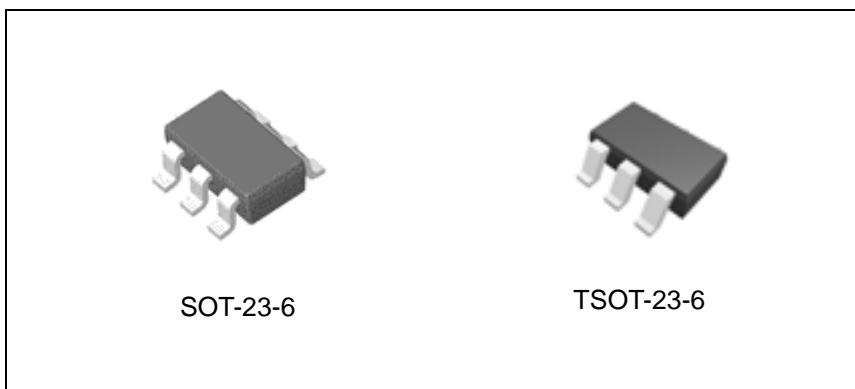


Figure 1. Package Types of AP3030

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Pin Configuration

K/KT Package
(SOT-23-6/TSOT-23-6)

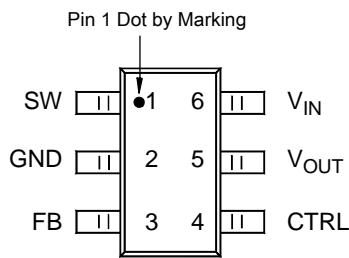


Figure 2. Pin Configuration of AP3030 (Top View)

Pin Description

Pin Number	Pin Name	Function
1	SW	Switch Pin. Connect external inductor
2	GND	Ground
3	FB	Voltage Feedback. Reference voltage is 200mV
4	CTRL	Shutdown and Dimming Pin. Connect to 1.8V or higher to enable device; Connect to 50mV or less to disable device; Connect to a voltage between 1.8V and 50mV to achieve linear dimming
5	V _{OUT}	Output Pin. Connected to the cathode of internal schottky diode
6	V _{IN}	Input Supply Pin. Must be locally bypassed

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Functional Block Diagram

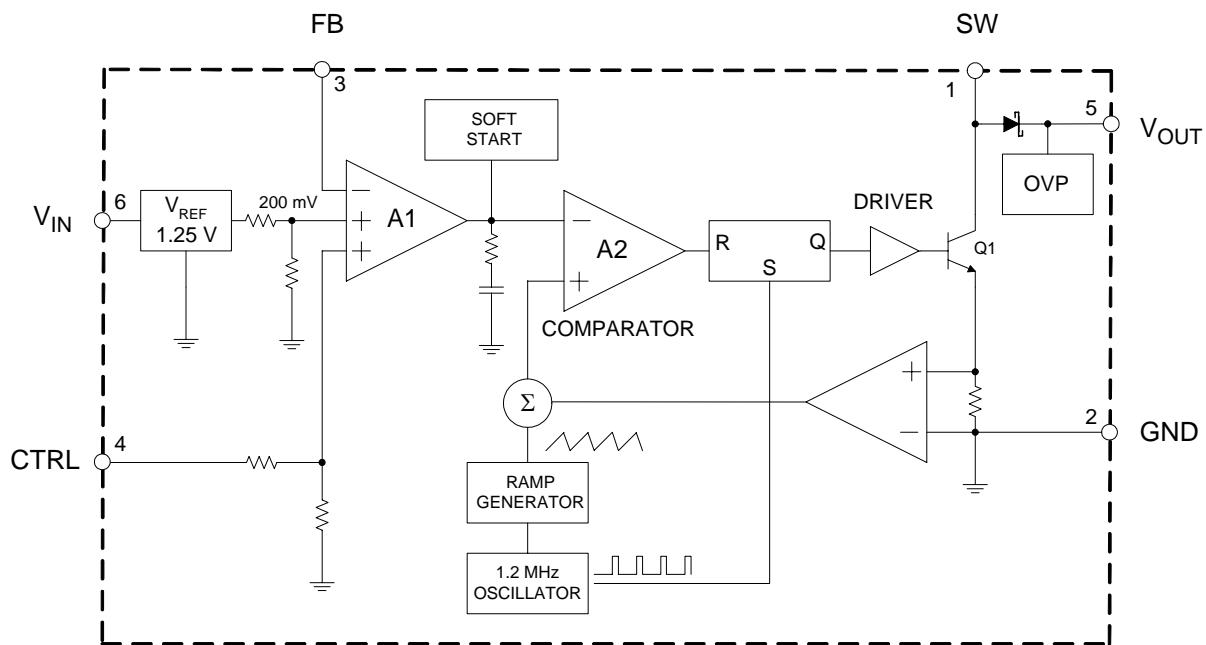


Figure 3. Functional Block Diagram of AP3030

Ordering Information

AP3030 <input type="checkbox"/> <input type="checkbox"/> - <input type="checkbox"/>	
Circuit Type <input type="checkbox"/>	E1: Lead Free G1: Green
Package <input type="checkbox"/>	TR: Tape and Reel
K: SOT-23-6	
KT: TSOT-23-6	

Package	Temperature Range	Part Number		Marking ID		Packing Type
		Lead Free	Green	Lead Free	Green	
SOT-23-6	-40 to 85°C	AP3030KTR-E1	AP3030KTR-G1	EEB	GEB	Tape & Reel
TSOT-23-6	-40 to 85°C	AP3030KTTR-E1	AP3030KTTR-G1	S9G	L9G	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.



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Absolute Maximum Ratings (Note 1)

Parameter	Symbol	Value	Unit
Input Voltage	V _{IN}	20	V
SW Voltage	V _{SW}	30	V
FB Voltage	V _{FB}	20	V
CTRL Voltage	V _{CTRL}	20	V
Thermal Resistance (Junction to Atmosphere, No Heat Sink)	R _{θJA}	265	°C/W
Operating Junction Temperature	T _J	150	°C
Storage Temperature Range	T _{STG}	-65 to 150	°C
Lead Temperature (Soldering, 10sec)	T _{LEAD}	260	°C
ESD (Machine Model)		250	V
ESD (Human Body Model)		2000	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Operating Temperature Range	T _{OP}	-40	85	°C
Input Voltage	V _{IN}	2.5	16	V
CTRL Voltage	V _{CTRL}		16	V



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Electrical Characteristics

(V_{IN}=3V, V_{CTRL}=3V, T_A=25°C, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Minimum Operating Voltage	V _{IN(min)}		2.5			V
Maximum Operating Voltage	V _{IN(max)}				16	
Feedback Voltage	V _{FB}	I _{OUT} =20mA, 4 LEDs, T _A =-40°C to 85°C	188	200	212	mV
FB Pin Bias Current	I _{FB}			35	100	nA
Quiescent Current	I _Q	V _{FB} =V _{IN} , no switching	1.5	2.5	3.2	mA
Shutdown Quiescent Current	I _{SHDN}	V _{CTRL} =0V	2.0	3.2	5.0	μA
Switch Frequency	f		0.9	1.2	1.5	MHz
Maximum Duty Cycle	D _{MAX}		90	93		%
Switch Current Limit (Note 2)	I _{LIMIT}	D=40%		550		mA
		D=80%		550		
Switch V _{CE} Saturation Voltage	V _{CESAT}	I _{SW} =250mA		360		mV
Switch Leakage Current		V _{SW} =5V		0.01	5	μA
CTRL Pin Voltage	V _{CTRL}	High	1.8			V
		Low			0.05	
CTRL Pin Bias Current	I _{CTRL}		40	55	72	μA
		T _A =85°C		50		
		T _A =-40°C		75		
Schottky Forward Drop	V _{DROP}	I _D =150mA		0.7		V
Schottky Leakage Current		V _R =23V		0.1	4	μA
		V _R =27V			150	
Soft Start Time	t			300		μS

Note 2: The switch current limit is related to duty cycle. Please refer to Figure 16 for detail.

WHITE LED STEP-UP CONVERTER
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Typical Performance Characteristics

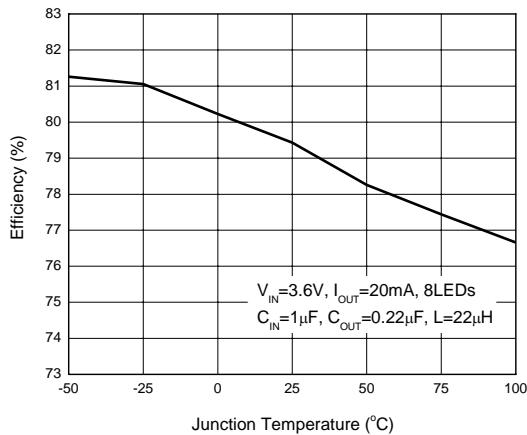
(V_F(forward voltage) of WLED is 3.45V @ I_F=20mA, unless otherwise noted)


Figure 4. Efficiency vs. Junction Temperature

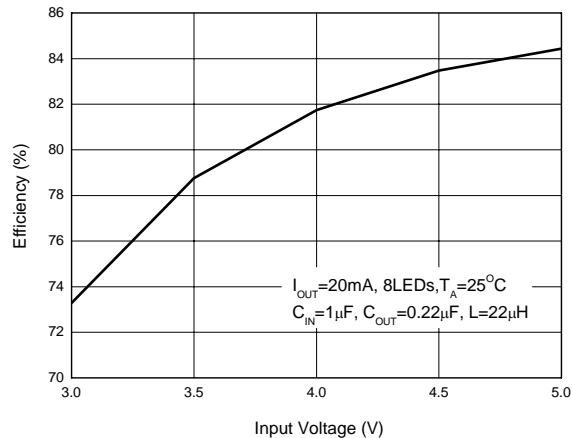


Figure 5. Efficiency vs. Input Voltage

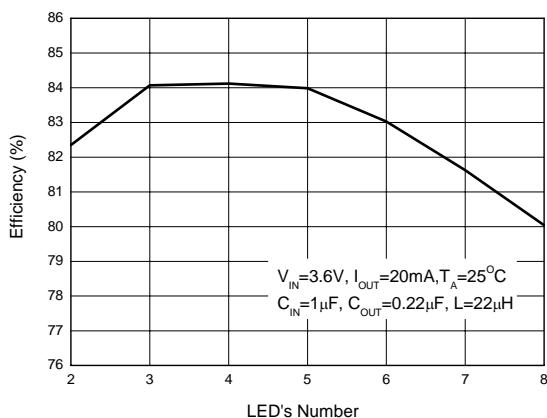
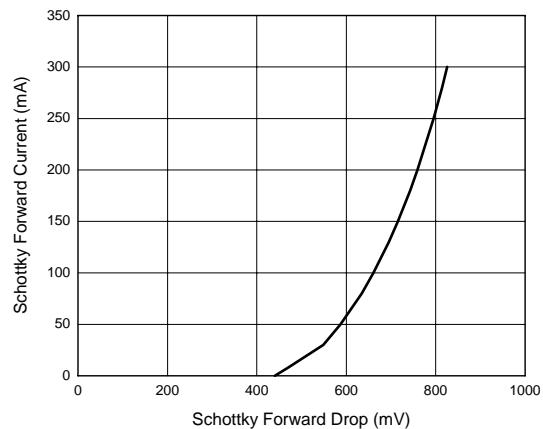


Figure 6. Efficiency vs. LED's Number


Figure 7. Schottky Forward Current
vs. Schottky Forward Drop

WHITE LED STEP-UP CONVERTER
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Typical Performance Characteristics (Continued)

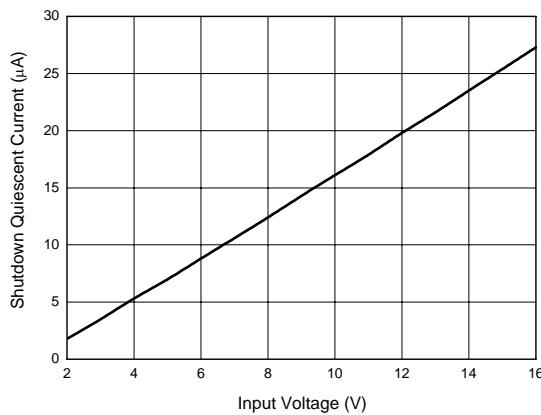
(V_F(forward voltage) of WLED is 3.45V @ I_F=20mA, unless otherwise noted)


Figure 8. Shutdown Quiescent Current vs. Input Voltage

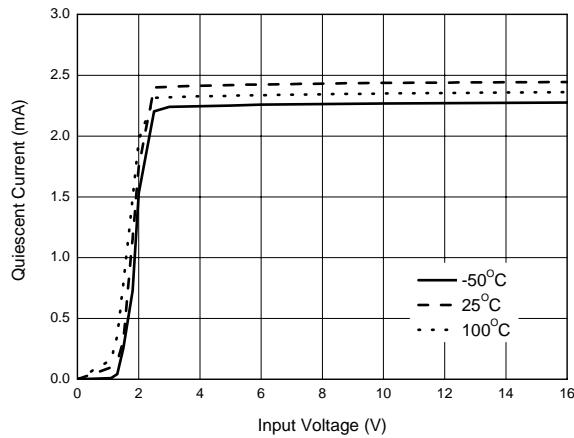


Figure 9. Quiescent Current vs. Input Voltage

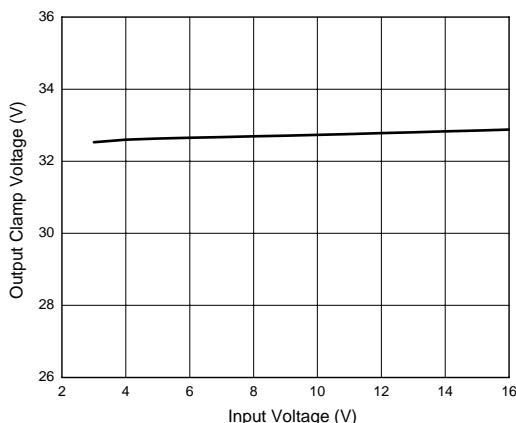


Figure 10. Output Clamp Voltage vs. Input Voltage

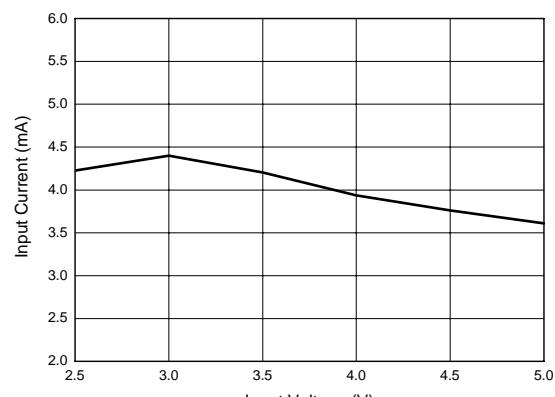


Figure 11. Input Current in Output Open Circuit vs. Input Voltage

WHITE LED STEP-UP CONVERTER
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Typical Performance Characteristics (Continued)

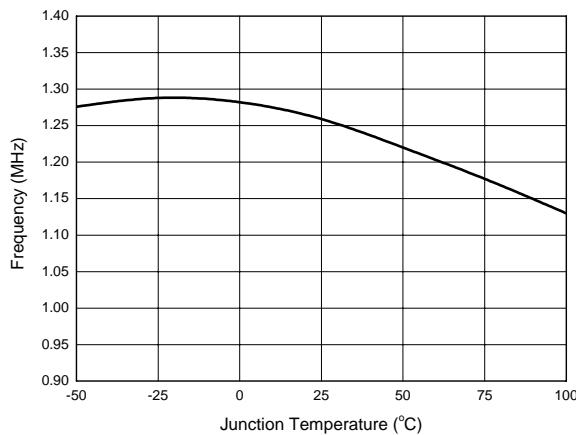
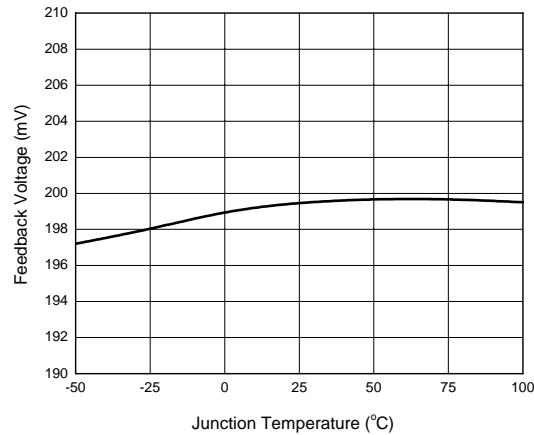
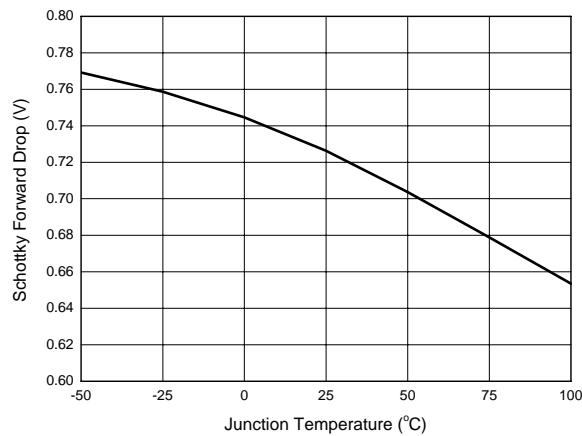
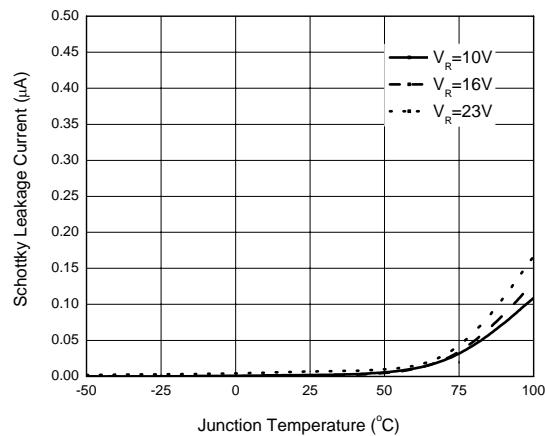
(V_F(forward voltage) of WLED is 3.45V @ I_F=20mA, unless otherwise noted)


Figure 12. Switch Frequency vs. Junction Temperature


Figure 13. Feedback Voltage
vs. Junction Temperature

Figure 14. Schottky Forward Drop
vs. Junction Temperature

Figure 15. Schottky Leakage Current
vs. Junction Temperature

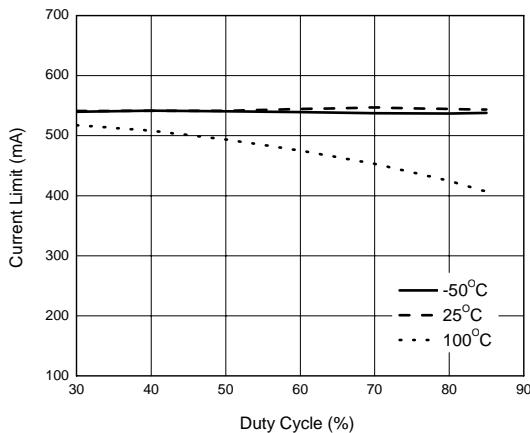
WHITE LED STEP-UP CONVERTER**AP3030****Typical Performance Characteristics (Continued)**(V_F(forward voltage) of WLED is 3.45V @ I_F=20mA, unless otherwise noted)

Figure 16. Switch Current Limit vs. Duty Cycle

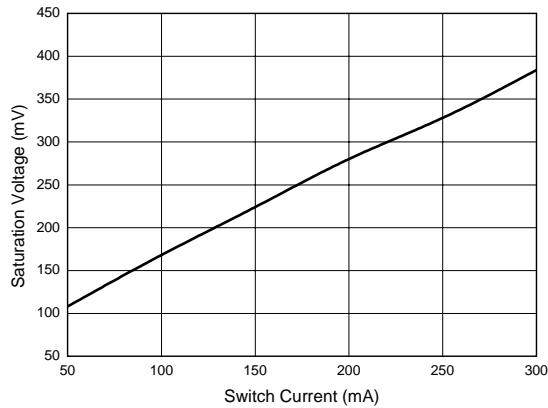


Figure 17. Switch Saturation Voltage vs. Switch Current

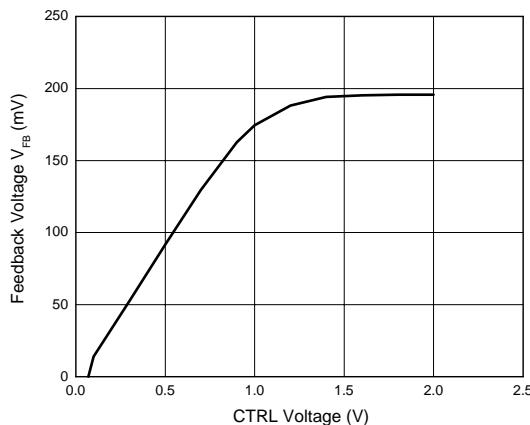
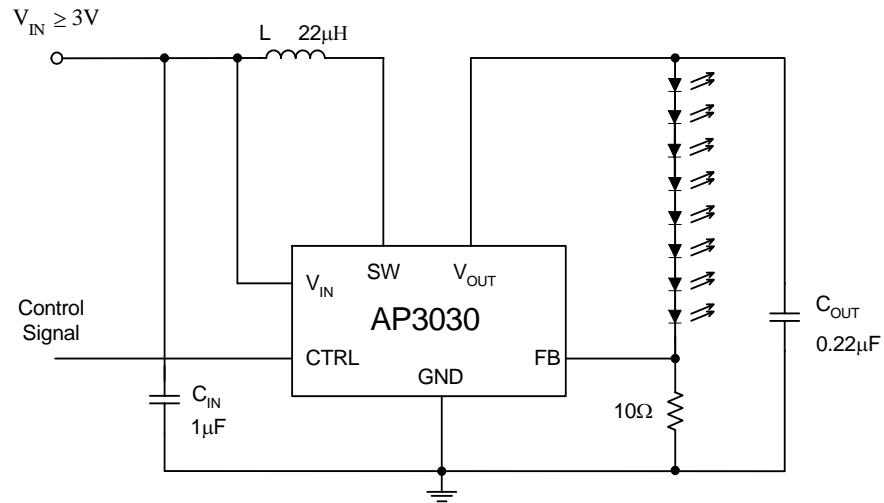


Figure 18. Feedback Voltage vs. CTRL Pin Voltage

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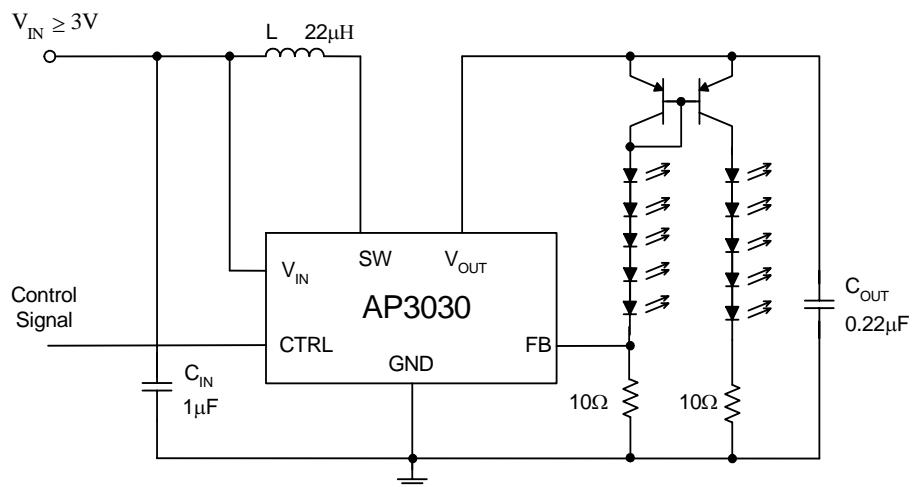
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Typical Application



C: X5R or X7R Dielectric
L: SUMIDA CDRH5D28R-220NC or Equivalent
This circuit can work in full temperature

Figure 19. Typical Application of Eight LED Drivers



C: X5R or X7R Dielectric
L: SUMIDA CDRH5D28R-220NC or Equivalent
Two transistors are recommended to use Dual Matched transistor pairs
This circuit can work in full temperature

Figure 20. Typical Application of Ten LED Drivers

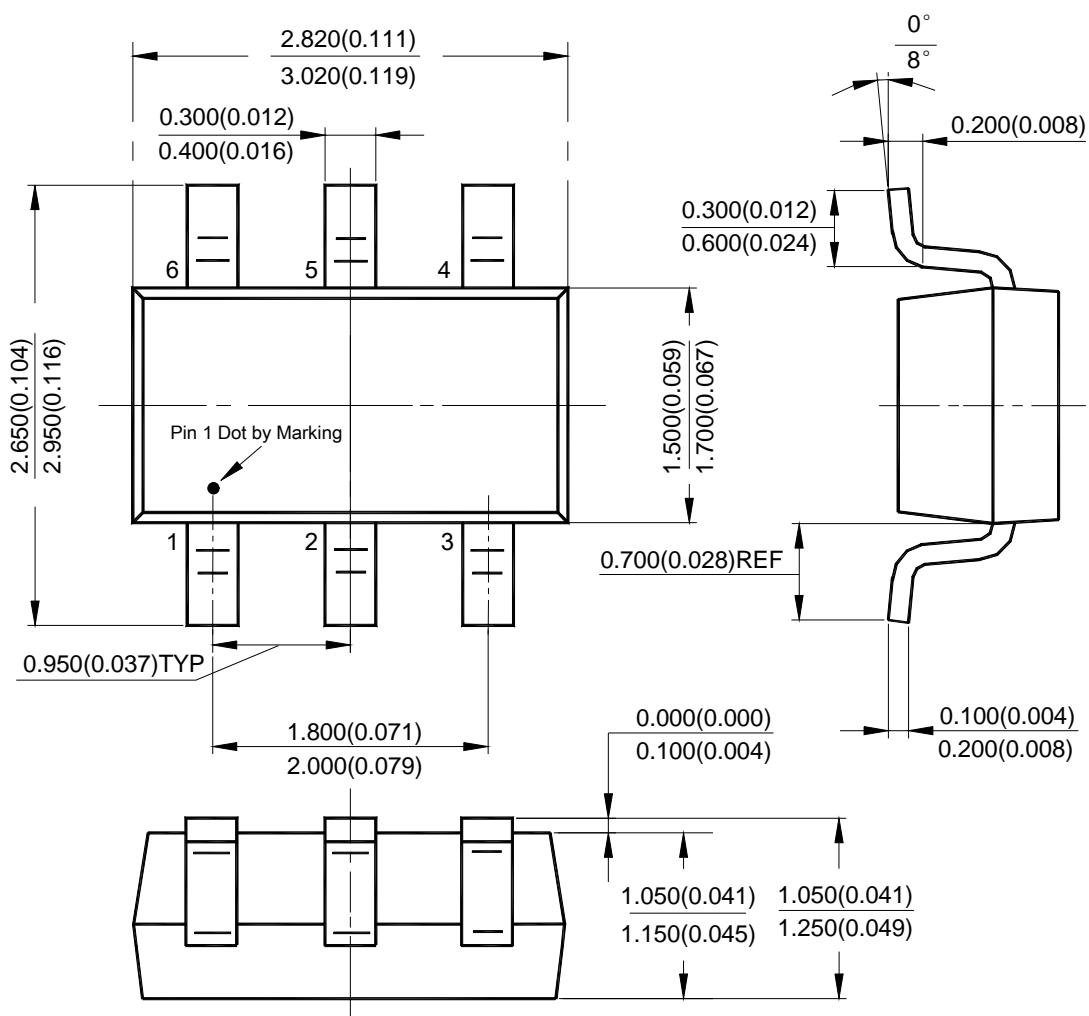
WHITE LED STEP-UP CONVERTER

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Mechanical Dimensions

SOT-23-6

Unit: mm(inch)



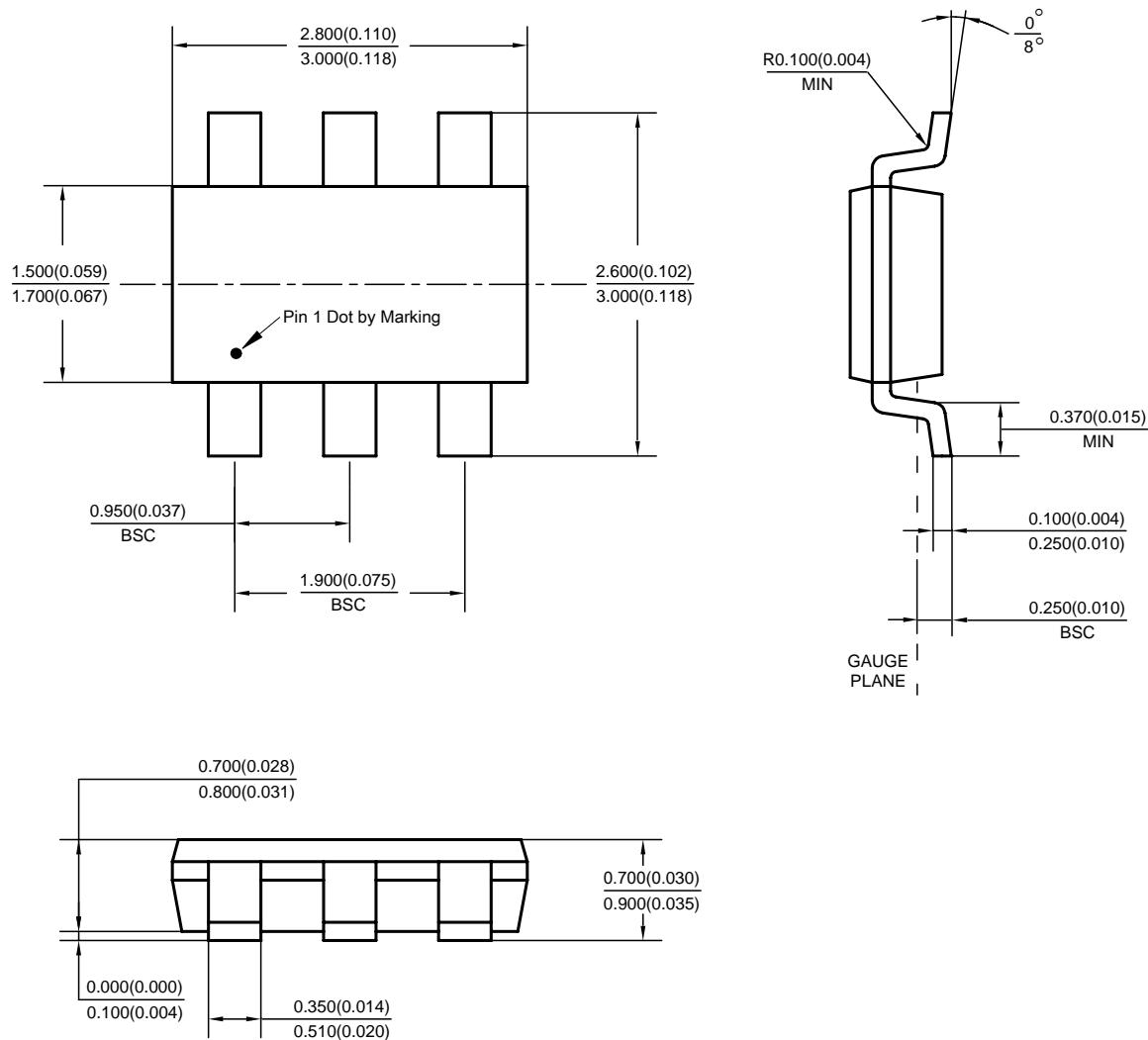
WHITE LED STEP-UP CONVERTER

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Mechanical Dimensions

TSOT-23-6

Unit: mm(inch)





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